

## MONOLITHIC QUAD H-BRIDGE DRIVER CIRCUIT

### DESCRIPTION

The  $\mu$ PD168101 is monolithic quad H-bridge driver LSI which uses power MOSFETs in the output stages. By using the MOS process, this driver IC has substantially improved the voltage loss of the output stage and power consumption as compared with conventional driver circuits using bipolar transistors.

By eliminating the charge pump circuit, the current during power-OFF is drastically decreased.

In addition, a low-voltage malfunction prevention circuit is also provided that prevents the IC from malfunctioning when the supply voltage drops.

As the package, a 24-pin plastic TSSOP is adopted to enable the creation of compact, slim application sets.

This driver IC can drive two stepping motor at the same time, and is ideal for driving stepping motors in the lens of a camera. It is the best for lens drive drivers, such as a digital camera and a video camera. Moreover, since the input of two terminals is respectively owned to H bridge 1 circuit, a maximum of four loads, such as DC motor, can be driven simultaneously.

### FEATURES

- Four H bridge circuits employing power MOSFETs
- Low current consumption by eliminating charge pump  
V<sub>M</sub> pin current when power-OFF: 10  $\mu$ A MAX. V<sub>DD</sub> pin current: 10  $\mu$ A MAX.
- Input logic frequency: 100 kHz
- 3-V power supply  
Minimum operating supply voltage: 2.5 V
- Low voltage malfunction prevention circuit
- 24-pin plastic TSSOP (5.72 mm (225))

### ORDERING INFORMATION

Part Number	Package
$\mu$ PD168101MA-6A5	24-pin plastic TSSOP (5.72 mm (225))

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**ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub> = 25°C)**

When mounted on a glass epoxy board (10 cm × 10 cm × 1 mm, 15% copper foil)

Parameter	Symbol	Condition	Rating	Unit
Control block supply voltage	V <sub>DD</sub>		-0.5 to +6.0	V
	V <sub>M</sub>		-0.5 to +6.0	V
Input voltage	V <sub>IN</sub>		-0.5 to V <sub>DD</sub> + 0.5	V
Output terminal voltage	V <sub>OUT</sub>		6.2	V
Output current	I <sub>M(DC)</sub>	DC	±0.35	A/ch
	I <sub>M(pulse)</sub>	PW ≤ 10 ms, Duty ≤ 5%	±0.7	A/ch
Power consumption	P <sub>T</sub>		0.7	W
Peak junction temperature	T <sub>CH(MAX)</sub>		150	°C
Storage temperature range	T <sub>stg</sub>		-55 to +150	°C

**RECOMMENDED OPERATING CONDITIONS**

When mounted on a glass epoxy board (10 cm × 10 cm × 1 mm, 15% copper foil)

Parameter	Symbol	Condition	MIN.	TYP.	MAX.	Unit
Control block supply voltage	V <sub>DD</sub>		2.5		5.5	V
	V <sub>M</sub>		2.7		5.5	V
Output current	I <sub>M(DC)</sub>	DC	-0.25		+0.25	A
Operating frequency	f <sub>IN</sub>	IN terminal			100	kHz
Operating temperature range	T <sub>A</sub>		-10		85	°C
Peak junction temperature	T <sub>CH(MAX)</sub>				125	°C

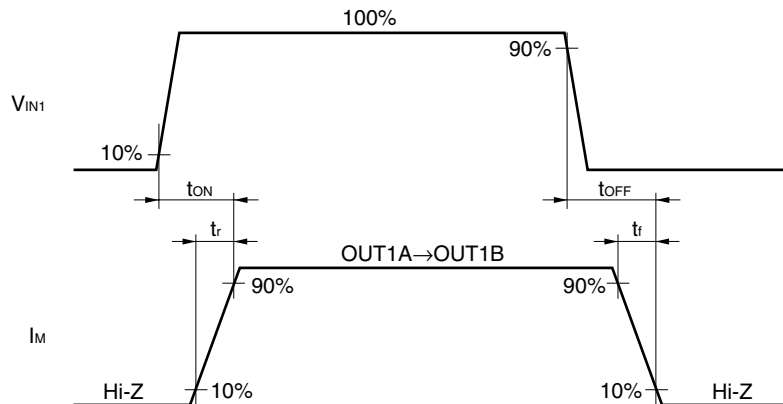
**CHARACTERISTICS (Unless otherwise specified,  $V_{DD} = V_M = 3\text{ V}$ ,  $T_A = 25^\circ\text{C}$ )**

Parameter	Symbol	Condition	MIN.	TYP.	MAX.	Unit
Off state $V_M$ pin current	$I_{M(OFF)}$	All control terminal = 0 V Per $V_M$ terminal			10	$\mu\text{A}$
$V_{DD}$ terminal current at the time of standby	$I_{DD(ST)}$	All control terminal = 0 V			10	$\mu\text{A}$
$V_{DD}$ terminal current at the time of operation	$I_{DD}$				1	mA
High level input current	$I_{IH}$	$V_{IN} = V_{DD}$			0.06	mA
Low level input current	$I_{IL}$	$V_{IN} = 0\text{ V}$	-1.0			$\mu\text{A}$
Input pull down resistance	$R_{IND}$		50		200	k $\Omega$
High level input voltage	$V_{IH}$	$2.5\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	$0.7 \times V_{DD}$		$V_{DD}+0.3$	V
Low level input voltage	$V_{IL}$	$2.5\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	-0.3		$0.3 \times V_{DD}$	V
H-bridge ON resistance	$R_{ON}$	$2.7\text{ V} \leq V_M = V_{DD} \leq 5.5\text{ V}$ $I_M = 0.25\text{ A}$ , Upper + lower		0.7	1.1	$\Omega$
Low voltage malfunction prevention circuit operating voltage	$V_{DDS1}$	$V_M = 5\text{ V}$ , $-10^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$	0.8		2.5	V
	$V_{DDS2}$	$V_M = 3\text{ V}$ , $-10^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$	0.65		2.5	V
H bridge output turn-on time 1	$t_{ON1}$	$R_M = 20\ \Omega$ , Figure 1 $t_{ON1}$ : turn-on time from all control = 0 V $t_{ON2}$ : turn-on time at operation		1.0		$\mu\text{s}$
H bridge output turn-on time 2	$t_{ON2}$			0.7	2.0	$\mu\text{s}$
H bridge output turn-off time	$t_{OFF}$			0.2	0.5	$\mu\text{s}$
H bridge output rise time	$t_r$			0.3	1.0	$\mu\text{s}$
H bridge output fall time	$t_f$			0.07	0.2	$\mu\text{s}$

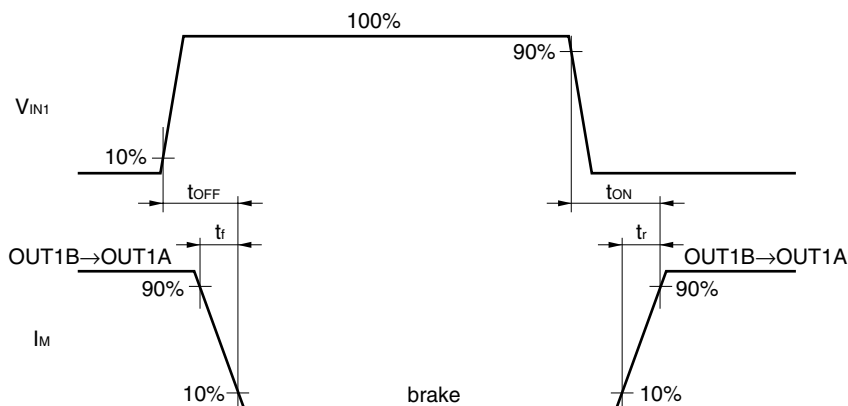
- Remarks 1.** As for thermal shutdown circuit (TSD), junction temperature operates above  $150^\circ\text{C}$ . At the time of over thermal detection, current supply is stopped by making all output terminals into high impedance. In addition, thermal shutdown circuit does not operate at the time of standby.
- 2.** A low voltage malfunction operation prevention circuit operates, if a voltage power supply ( $V_{DD}$ ) becomes less than 2.5 V. All output terminals be high impedance at the time of UVLO operation.

Figure 1. Switching time condition

(1) IN2 = Low-level



(2) IN2 = High-level



**FUNCTION TABLE**

The logic of each channel is as follows

Channel 1

IN1	IN2	OUT1A	OUT1B
L	L	Z	Z
L	H	L	H
H	L	H	L
H	H	L	L

Channel 2

IN3	IN4	OUT2A	OUT2B
L	L	Z	Z
L	H	L	H
H	L	H	L
H	H	L	L

Channel 3

IN5	IN6	OUT3A	OUT3B
L	L	Z	Z
L	H	L	H
H	L	H	L
H	H	L	L

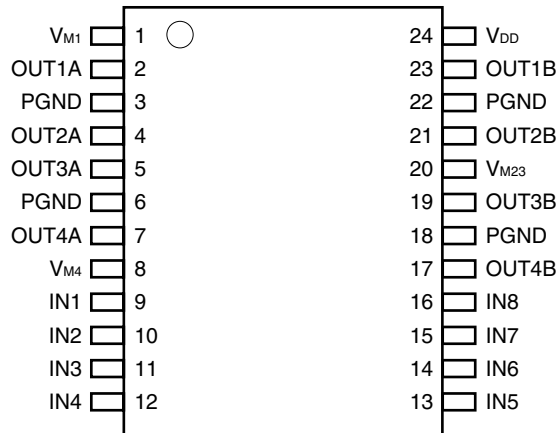
Channel 4

IN7	IN8	OUT4A	OUT4B
L	L	Z	Z
L	H	L	H
H	L	H	L
H	H	L	L

H: High-level, L: Low-level, Z: High impedance

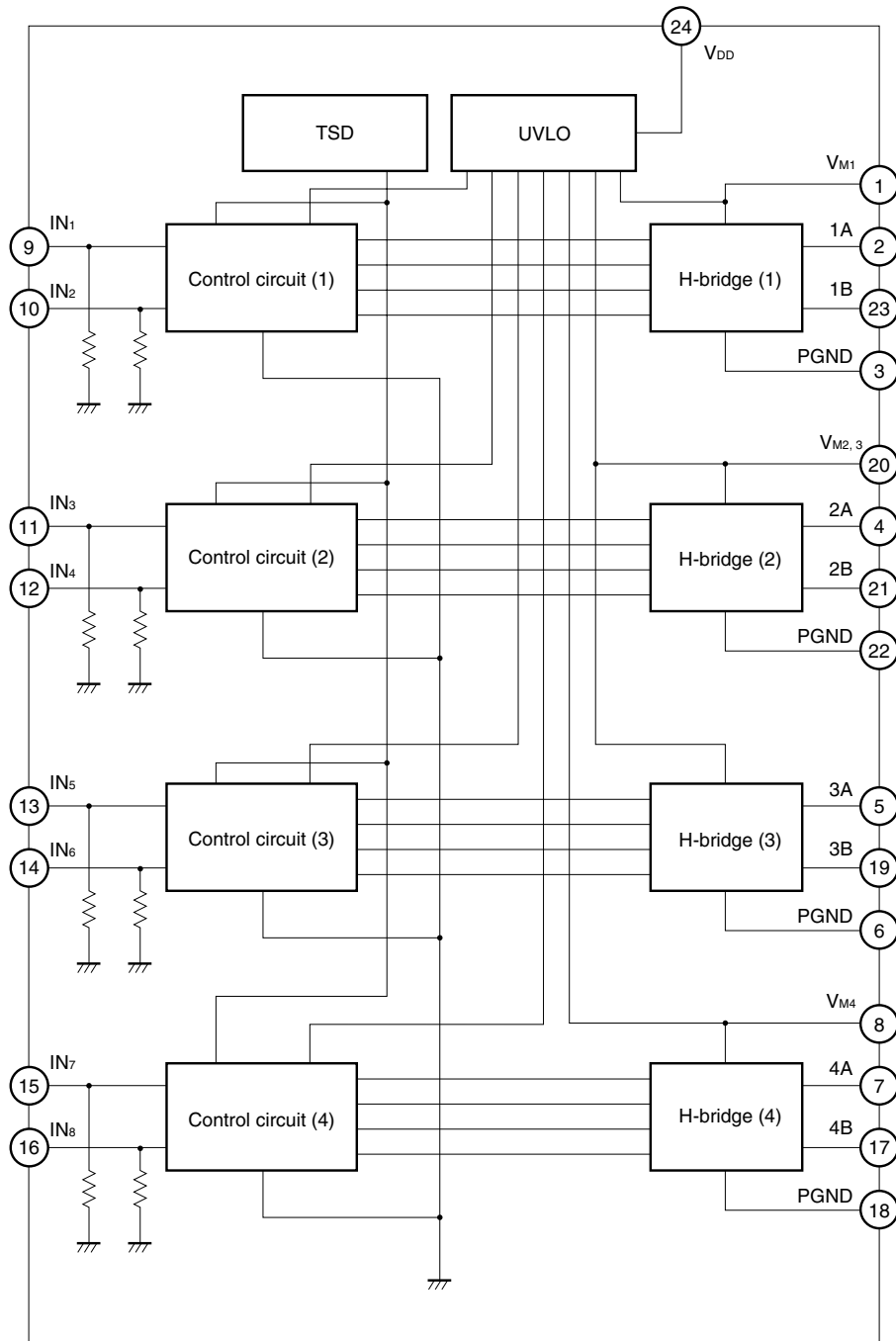
When all control pin is low-level, IC becomes stand-by state and current consumption is reduced.

PIN CONNECTION



Pin No.	Pin name	Pin function
1	VM1	Output block supply voltage input terminal
2	OUT1A	Output terminal
3	PGND	Ground terminal
4	OUT2A	Output terminal
5	OUT3A	Output terminal
6	PGND	Ground terminal
7	OUT4A	Output terminal
8	VM4	Output block supply voltage input terminal
9	IN1	Control terminal (channel 1)
10	IN2	Control terminal (channel 1)
11	IN3	Control terminal (channel 2)
12	IN4	Control terminal (channel 2)
13	IN5	Control terminal (channel 3)
14	IN6	Control terminal (channel 3)
15	IN7	Control terminal (channel 4)
16	IN8	Control terminal (channel 4)
17	OUT4B	Output terminal
18	PGND	Ground terminal
19	OUT3B	Output terminal
20	VM23	Output block supply voltage input terminal
21	OUT2B	Output terminal
22	PGND	Ground terminal
23	OUT1B	Output terminal
24	VDD	Control block supply voltage input terminal

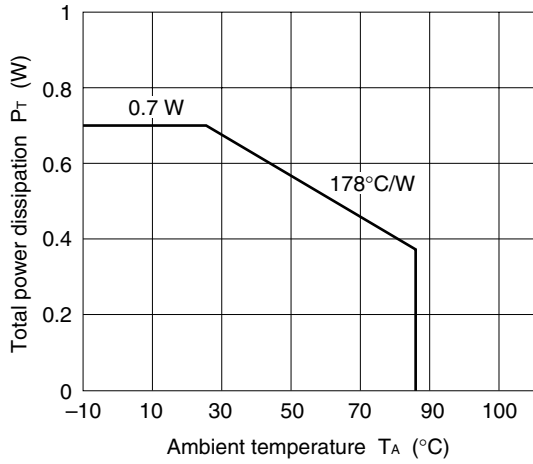
BLOCK DIAGRAM



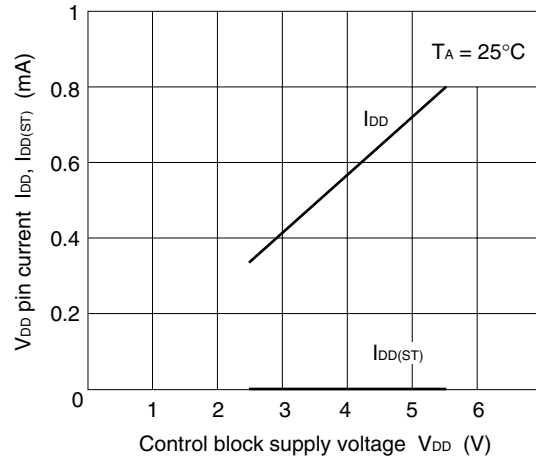
- Cautions**
1. The terminal which has more than one should connect not only one terminal but all terminals.
  2. Pull down resistance is connected to the input terminal. It's not necessary that the input terminal is connected when it isn't used.
  3. The motor part power supply terminals V<sub>M1</sub>, V<sub>M2,3</sub>, and V<sub>M4</sub> are separated inside, and can impress an individually different power supply.
  4. The motor part power supply terminal of the output which is not used should impress voltage of recommended operation condition, or should connect to GND.  
In addition, if voltage is impressed to V<sub>M</sub> terminal even when an input is open, V<sub>M</sub> terminal current (10 μA<sub>MAX</sub>) is flow at the time of standby.

TYPICAL CHARACTERISTICS

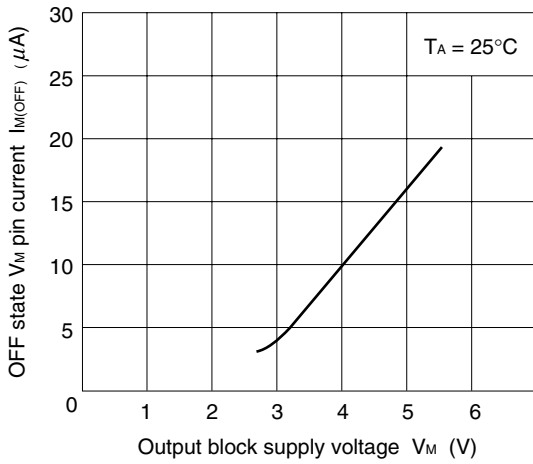
$P_T$  vs.  $T_A$  characteristics



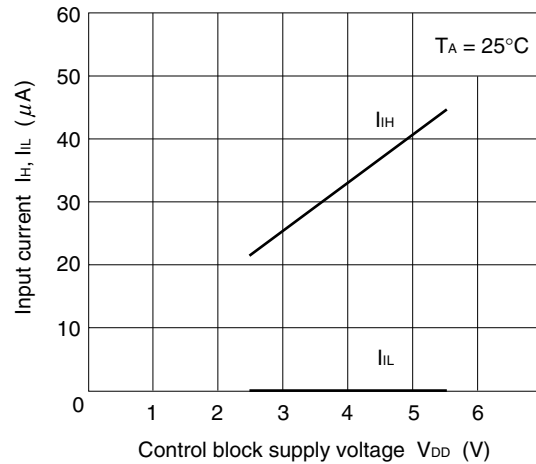
$I_{DD}$ ,  $I_{DD(ST)}$  vs.  $V_{DD}$  characteristics



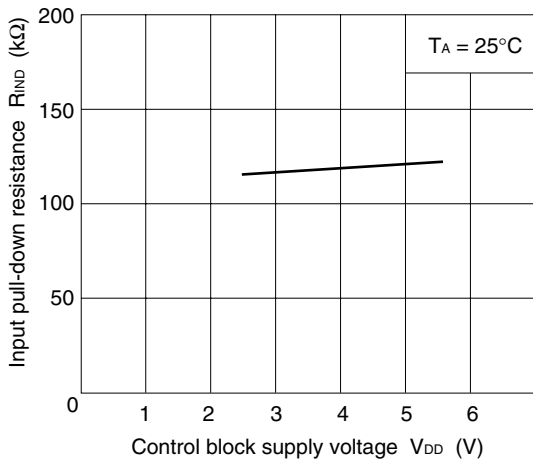
$I_M$  vs.  $V_M$  characteristics



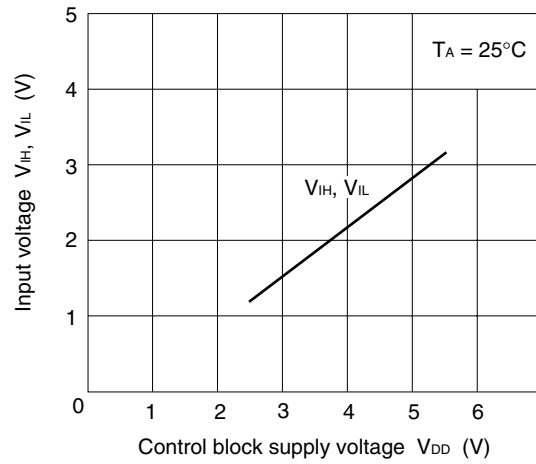
$I_{IH}$ ,  $I_{IL}$  vs.  $V_{DD}$  characteristics



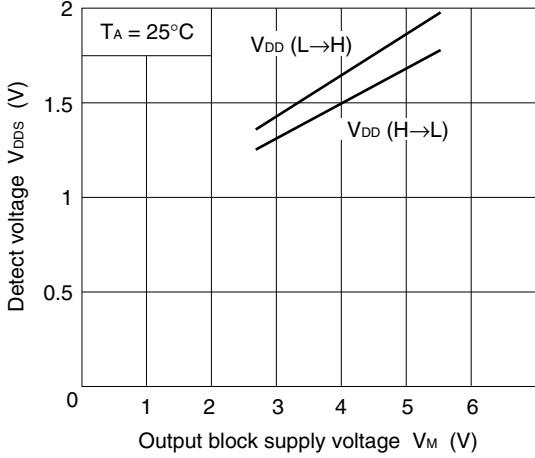
$R_{IND}$  vs.  $V_{DD}$  characteristics



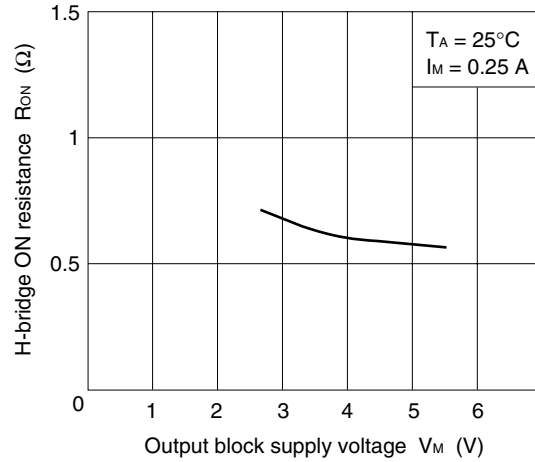
$V_{IH}$ ,  $V_{IL}$  vs.  $V_{DD}$  characteristics



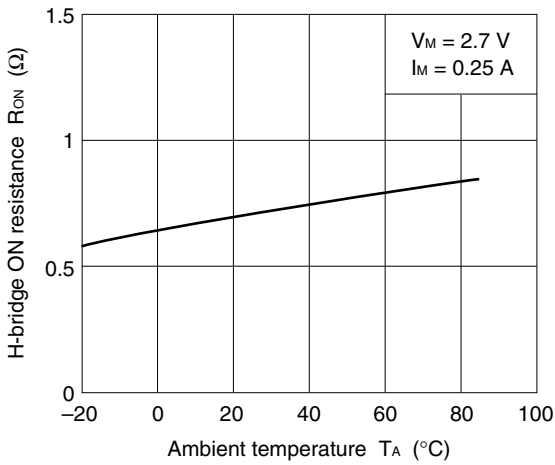
Detect voltage at low voltage characteristics



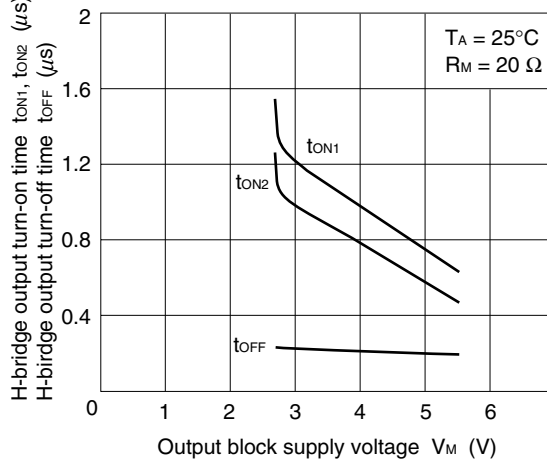
$R_{ON}$  vs.  $V_M$  characteristics



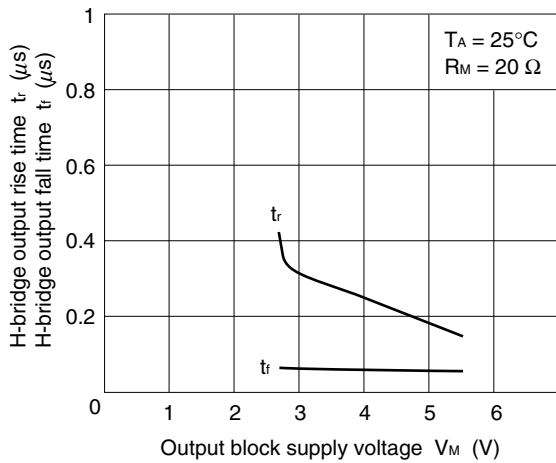
$R_{ON}$  vs.  $T_A$  characteristics



$t_{ON1}$ ,  $t_{ON2}$ ,  $t_{OFF}$  vs.  $V_M$  characteristics

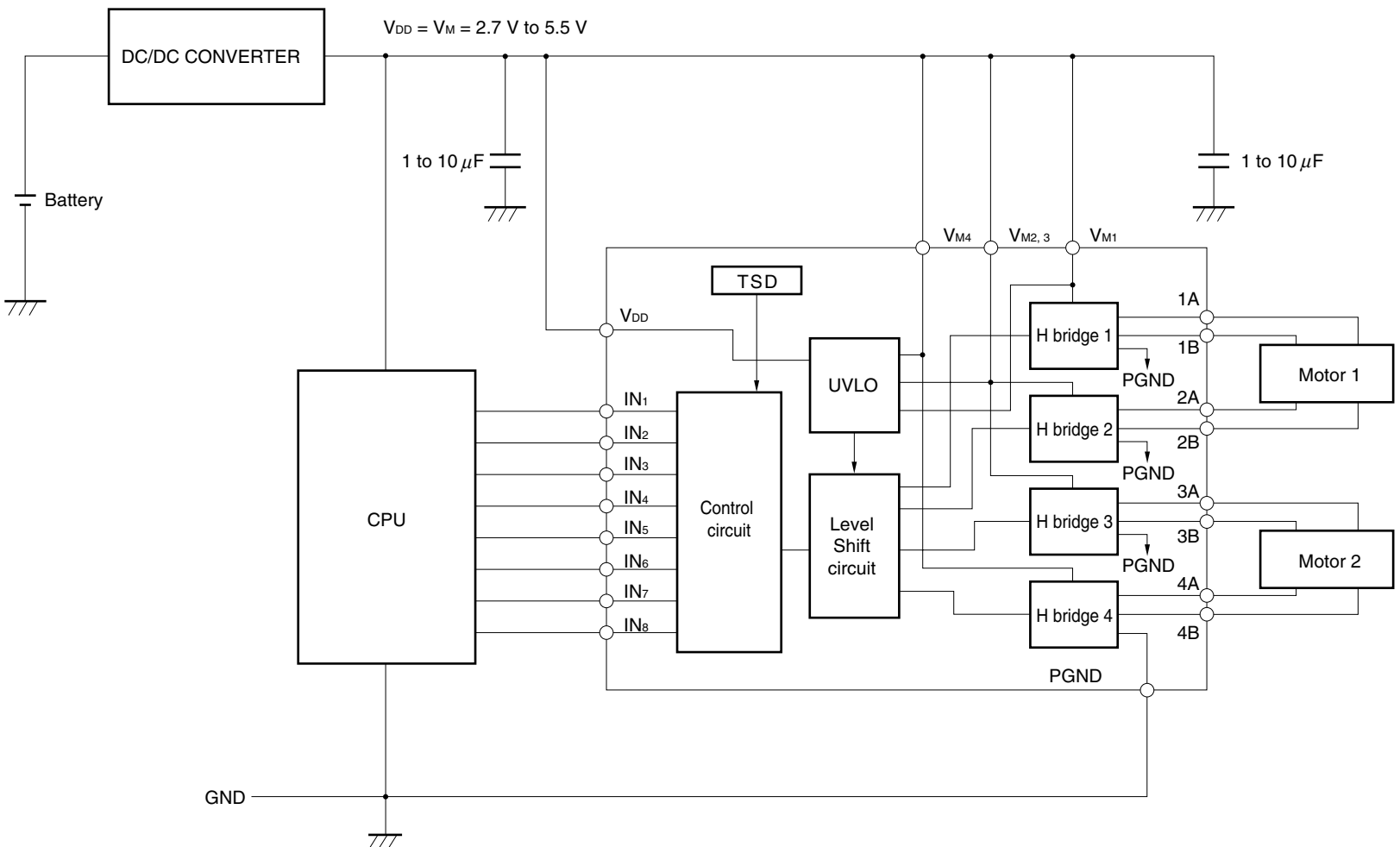


$t_r$ ,  $t_f$  vs.  $V_M$  characteristics





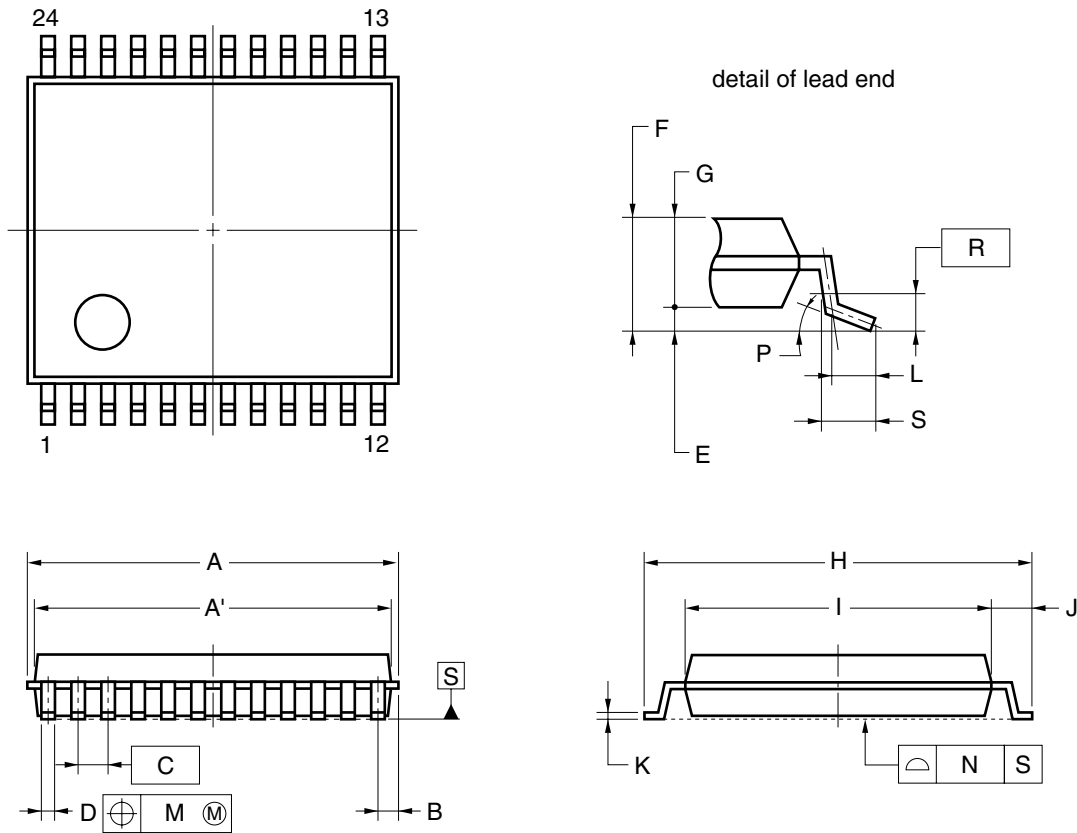
STANDARD CONNECTION EXAMPLE



This circuit diagram is an example of connection, and is not a thing aiming at mass production.

PACKAGE DIMENSION

24-PIN PLASTIC TSSOP (5.72 mm (225))



NOTE

Each lead centerline is located within 0.10 mm of its true position (T.P.) at maximum material condition.

ITEM	MILLIMETERS
A	6.65±0.10
A'	6.5±0.1
B	0.575
C	0.5 (T.P.)
D	0.22±0.05
E	0.1±0.05
F	1.2 MAX.
G	1.0±0.05
H	6.4±0.1
I	4.4±0.1
J	1.0±0.1
K	0.17±0.025
L	0.5
M	0.10
N	0.08
P	3°+5° -3°
R	0.25
S	0.6±0.15

P24MA-50-6A5

**RECOMMENDED SOLDERING CONDITIONS**

Solder this product under the following recommended conditions.

For soldering methods and conditions other than those recommended, consult NEC.

For details of the recommended soldering conditions, refer to information document “**Semiconductor Device Mounting Technology Manual**”.

Soldering Method	Soldering Conditions	Recommended Condition Symbol
Infrared reflow	Package peak temperature: 235°C; Time: 30 secs. max. (210°C min.); Number of times: 3 times max; Number of day: none; Flux: Rosin-based flux with little chlorine content (chlorine: 0.2Wt% max.) is recommended.	IR35-00-3
VPS	Package peak temperature: 215°C; Time: 40 secs. max. (200°C min.); Number of times: 3 times max.; Number of day: none; Flux: Rosin-based flux with little chlorine content (chlorine: 0.2 Wt% max.) is recommended.	VP15-00-3
Wave soldering	Package peak temperature: 260°C; Time: 10 secs. max.; Preheating temperature: 120°C max.; Number of times: once; Flux: Rosin-based flux with little chlorine content (chlorine: 0.2 Wt% max.) is recommended.	WS60-00-1

**Caution Do not use two or more soldering methods in combination.**

[MEMO]

[MEMO]

**NOTES FOR CMOS DEVICES****① PRECAUTION AGAINST ESD FOR SEMICONDUCTORS**

Note:

Strong electric field, when exposed to a MOS device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred. Environmental control must be adequate. When it is dry, humidifier should be used. It is recommended to avoid using insulators that easily build static electricity. Semiconductor devices must be stored and transported in an anti-static container, static shielding bag or conductive material. All test and measurement tools including work bench and floor should be grounded. The operator should be grounded using wrist strap. Semiconductor devices must not be touched with bare hands. Similar precautions need to be taken for PW boards with semiconductor devices on it.

**② HANDLING OF UNUSED INPUT PINS FOR CMOS**

Note:

No connection for CMOS device inputs can be cause of malfunction. If no connection is provided to the input pins, it is possible that an internal input level may be generated due to noise, etc., hence causing malfunction. CMOS devices behave differently than Bipolar or NMOS devices. Input levels of CMOS devices must be fixed high or low by using a pull-up or pull-down circuitry. Each unused pin should be connected to  $V_{DD}$  or GND with a resistor, if it is considered to have a possibility of being an output pin. All handling related to the unused pins must be judged device by device and related specifications governing the devices.

**③ STATUS BEFORE INITIALIZATION OF MOS DEVICES**

Note:

Power-on does not necessarily define initial status of MOS device. Production process of MOS does not define the initial operation status of the device. Immediately after the power source is turned ON, the devices with reset function have not yet been initialized. Hence, power-on does not guarantee out-pin levels, I/O settings or contents of registers. Device is not initialized until the reset signal is received. Reset operation must be executed immediately after power-on for devices having reset function.

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- Device availability
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- Availability of related technical literature
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- Network requirements

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